

1N5283 THRU 1N5314**SILICON CURRENT LIMITING DIODES**
www.centrasemi.com
DESCRIPTION:

The CENTRAL SEMICONDUCTOR 1N5283 series types are silicon field effect current regulator diodes designed for applications requiring a constant current over a wide voltage range. These devices are manufactured in the cost effective DO-35 double plug case which provides many benefits to the user, including space savings and improved thermal characteristics. Special selections of I_P (regulator current) are available for critical applications.

**DO-35 CASE****FEATURES:**

- High Reliability
- Superior Lot To Lot Consistency
- Special Selections Available
- Surface Mount Devices Available

MAXIMUM RATINGS: ($T_L=75^\circ\text{C}$)

Peak Operating Voltage

Power Dissipation

Operating and Storage Junction Temperature

SYMBOL P_{OV} P_D T_J, T_{stg}

100

600

-65 to +200

UNITS

V

mW

 $^\circ\text{C}$ **ELECTRICAL CHARACTERISTICS:** ($T_A=25^\circ\text{C}$)

Type	Regulator Current (Note 1) $I_P @ V_T=25\text{V}$			Minimum Dynamic Impedance $Z_T @ V_T=25\text{V}$	Minimum Knee Impedance $Z_K @ V_K=6.0\text{V}$	Maximum Limiting Voltage $V_L @ I_L=0.8 \times I_P \text{ MIN}$
	MIN mA	NOM mA	MAX mA	MΩ	MΩ	V
1N5283	0.187	0.22	0.253	25	2.75	1.0
1N5284	0.204	0.24	0.276	19	2.35	1.0
1N5285	0.230	0.27	0.311	14	1.95	1.0
1N5286	0.255	0.30	0.345	9.0	1.60	1.0
1N5287	0.281	0.33	0.380	6.6	1.35	1.0
1N5288	0.332	0.39	0.449	4.1	1.00	1.05
1N5289	0.366	0.43	0.495	3.3	0.87	1.05
1N5290	0.400	0.47	0.541	2.7	0.75	1.05
1N5291	0.476	0.56	0.644	1.90	0.56	1.10
1N5292	0.527	0.62	0.713	1.55	0.47	1.13
1N5293	0.578	0.68	0.782	1.35	0.40	1.15
1N5294	0.638	0.75	0.863	1.15	0.335	1.20
1N5295	0.697	0.82	0.943	1.00	0.29	1.25
1N5296	0.774	0.91	1.05	0.88	0.24	1.29
1N5297	0.850	1.00	1.15	0.80	0.205	1.35
1N5298	0.935	1.10	1.27	0.70	0.18	1.40

Notes: (1) Pulsed Method: Pulse Width (ms) = 27.5 divided by I_P NOM (mA)

R4 (7-February 2013)

1N5283 THRU 1N5314
SILICON CURRENT LIMITING DIODES



ELECTRICAL CHARACTERISTICS - Continued: ($T_A=25^\circ\text{C}$)

Type	Regulator Current (Note 1) $I_P @ V_T=25V$			Minimum Dynamic Impedance $Z_T @ V_T=25V$	Minimum Knee Impedance $Z_K @ V_K=6.0V$	Maximum Limiting Voltage $V_L @ I_L=0.8 \times I_P \text{ MIN}$
	MIN mA	NOM mA	MAX mA	MΩ	MΩ	V
1N5299	1.02	1.20	1.38	0.640	0.155	1.45
1N5300	1.11	1.30	1.50	0.580	0.135	1.50
1N5301	1.19	1.40	1.61	0.540	0.115	1.55
1N5302	1.28	1.50	1.73	0.510	0.105	1.60
1N5303	1.36	1.60	1.84	0.475	0.092	1.65
1N5304	1.53	1.80	2.07	0.420	0.074	1.75
1N5305	1.70	2.00	2.30	0.395	0.061	1.85
1N5306	1.87	2.20	2.53	0.370	0.052	1.95
1N5307	2.04	2.40	2.76	0.345	0.044	2.00
1N5308	2.30	2.70	3.11	0.320	0.035	2.15
1N5309	2.55	3.00	3.45	0.300	0.029	2.25
1N5310	2.81	3.30	3.80	0.280	0.024	2.35
1N5311	3.06	3.60	4.14	0.265	0.020	2.50
1N5312	3.32	3.90	4.49	0.255	0.017	2.60
1N5313	3.66	4.30	4.95	0.245	0.014	2.75
1N5314	4.00	4.70	5.41	0.235	0.012	2.90

DO-35 CASE - MECHANICAL OUTLINE



DIMENSIONS				
SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.018	0.022	0.46	0.56
B	0.120	0.200	3.05	5.08
C	0.060	0.090	1.52	2.29
D	1.000	-	25.40	-

DO-35 (REV: R1)

R1

R4 (7-February 2013)

Mouser Electronics

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